National Semiconductor

CD4024BM/CD4024BC 7-Stage Ripple Carry Binary Counter

General Description

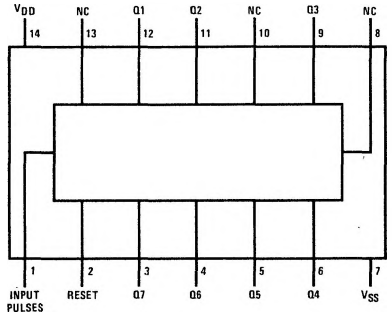
The CD4024BM/CD4024BC is a 7-stage ripple-carry binary counter. Buffered outputs are externally available from stages 1 through 7. The couter is reset to its logical "0" stage by a logical "1" on the reset input. The counter is advanced one count on the negative transition of each clock pulse.

Features

- Wide supply voltage range — 3.0 V to 15 V
- High noise immunity — 0.45 V_{DD} (typ.)
- Low power TTL compatibility — fan out of 2 driving 74L or 1 driving 74LS
- High speed — 12 MHz (typ.) input pulse rate $V_{DD} - V_{SS} = 10$ V
- Fully static operation

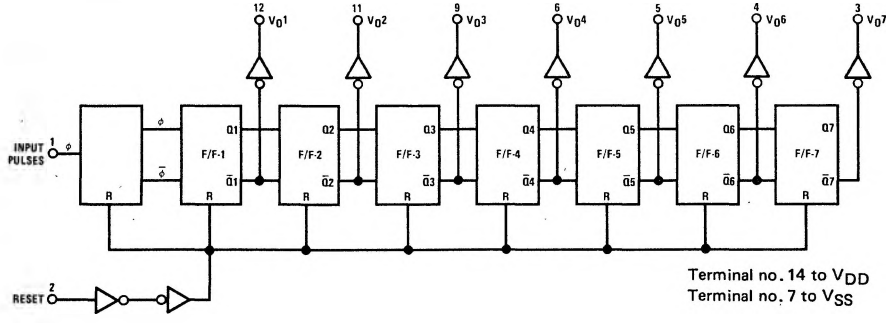
Connection Diagram

Dual-In-Line Package



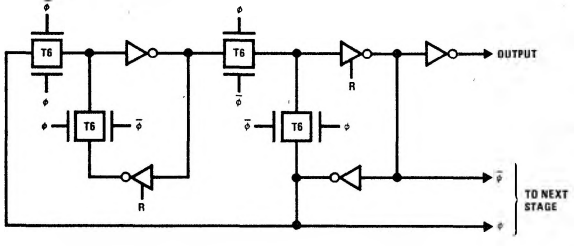
TOP VIEW

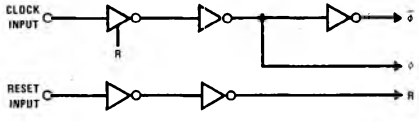
Logic Diagram



Terminal no. 14 to V_{DD}
Terminal no. 7 to V_{SS}

Schematic Diagram





Input Logic

Flip-flop logic (1 of 7 identical stages).

Absolute Maximum Ratings

(Notes 1 and 2)

V_{DD} dc Supply Voltage	−0.5 to +18 V_{DC}
V_{IN} Input Voltage	−0.5 to V_{DD} +0.5 V_{DC}
T_S Storage Temperature Range	−65°C to +150°C
P_D Package Dissipation	500 mW
T_L Lead Temperature (Soldering, 10 seconds)	300°C

Recommended Operating Conditions

(Note 2)

V_{DD} dc Supply Voltage	+3 to +15 V_{DC}
V_{IN} Input Voltage	0 to V_{DD} V_{DC}
T_A Operating Temperature Range	
CD4024BM	−55°C to +125°C
CD4024BC	−40°C to +85°C

DC Electrical Characteristics CD4024BM (Note 2)

PARAMETER		CONDITIONS	−55°C		25°C			125°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		5		0.3	5		150	μA
		V_{DD} = 10V		10		0.5	10		300	μA
		V_{DD} = 15V		20		0.7	20		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5		2	1.5		1.5	V
		V_{DD} = 10V, V_O = 1.0V or 9.0V		3.0		4	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5	3		3.5		V
		V_{DD} = 10V, V_O = 1.0V or 9.0V	7.0		7.0	6		7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.64		0.51	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.6		1.3	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.64		−0.51	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.6		−1.3	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.10		-10^{-5}	−0.10		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.10		10^{-5}	0.10		1.0	μA

DC Electrical Characteristics CD4024BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		20		0.3	20		150	μA
		V_{DD} = 10V		40		0.5	40		300	μA
		V_{DD} = 15V		60		0.7	80		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V

DC Electrical Characteristics (Cont'd.) CD4024BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
V_{IL}	Low Level Input Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5		2	1.5		1.5	V
		V_{DD} = 10V, V_O = 1.0V or 9.0V		3.0		4	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5	3		3.5		V
		V_{DD} = 10V, V_O = 1.0V or 9.0V	7.0		7.0	6		7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.30		-10^{-5}	−0.30		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.30		10^{-5}	0.30		1.0	μA

AC Electrical Characteristics $T_A = 25°C$, $C_L = 50\,pF$, $R_L = 200\,k$, t_r and $t_f = 20\,ns$ unless otherwise specified.

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
t_{PHL}, t_{PLH}	Propagation Delay Time (Note 3)	V_{DD} = 5V		185	350	ns
		V_{DD} = 10V		85	125	ns
		V_{DD} = 15V		70	100	ns
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
t_{WL}, t_{WH}	Minimum Input Pulse Width	V_{DD} = 5V		75	200	ns
		V_{DD} = 10V		40	110	ns
		V_{DD} = 15V		35	90	ns
t_{RCL}, t_{FCL}	Input Rise and Fall Time	V_{DD} = 5V			15	μs
		V_{DD} = 10V			10	μs
		V_{DD} = 15V			8	μs
f_{CL}	Maximum Input Pulse Frequency	V_{DD} = 5V	1.5	5		MHz
		V_{DD} = 10V	4	12		MHz
		V_{DD} = 15V	5	15		MHz
t_{PHL}	Reset Propagation Delay Time	V_{DD} = 5V		185	350	ns
		V_{DD} = 10V		85	125	ns
		V_{DD} = 15V		70	100	ns
t_{WH}	Reset Minimum Pulse Width	V_{DD} = 5V		185	350	ns
		V_{DD} = 10V		85	125	ns
		V_{DD} = 15V		70	100	ns
C_{IN}	Input Capacitance (Note 4)	Any Input		5	7.5	pF

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: To Q1 output.

Note 4: Capacitance is guaranteed by periodic testing.